

FAST RECOVERY DIODES
Stud Version
Major Ratings and Characteristics

Parameters	40HFL	70HFL	85HFL	Units
$I_{F(AV)}$	40	70	85	A
@ Max Tc	75	75	75	A
I_{FSM} @ 50Hz	400	700	1100	A
@ 60Hz	420	730	1151	A
I^2t @ 50Hz	800	2450	6050	A ² s
@ 60Hz	730	2240	5523	A ² s
I^2Vt	11300	34650	85560	I ² Vs
V_{RRM} range	100 to 1000			V
t_{rr} range	see table			ns
T_J range	- 40 to 125			°C



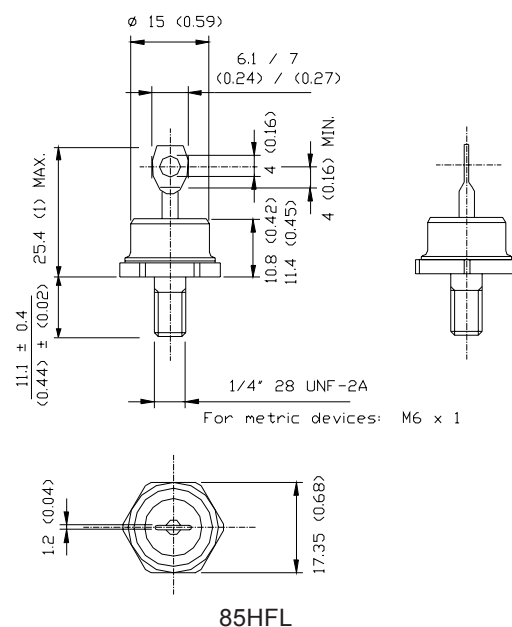
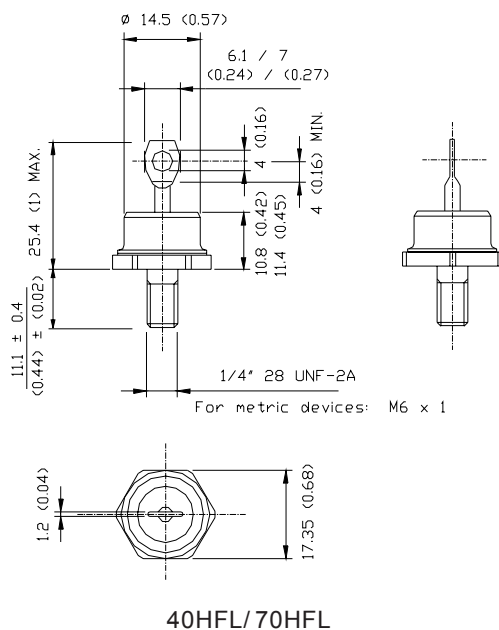
case style
DO-203AB (DO-5)

Description

This range of fast recovery diodes is designed for applications in DC power supplies, inverters, converters, choppers, ultrasonic systems and for use as a free wheeling diode.

Features

- Short reverse recovery time
- Low stored charge
- Wide current range
- Excellent surge capabilities
- Stud cathode and stud anode versions
- Types up to 1000V_{RRM}



ELECTRICAL SPECIFICATIONS

Reverse voltage ratings

Part number ①	V_{RRM} , Maximum peak repetitive reverse voltage $T_J = -40$ to 125°C	V_{RRM} , Maximum peak non-repetitive reverse voltage $T_J = 25$ to 125°C	I_{FM} Maximum peak reverse current at rated V_{RRM}	
	V	V	$T_J = 25^\circ\text{C}$ mA	$T_J = 125^\circ\text{C}$ mA
40HFL10S02, 40HFL10S05, 40HFL10S10	100	150	0.1	10
40HFL20S02, 40HFL20S05, 40HFL20S10	200	300	0.1	10
40HFL40S02, 40HFL40S05, 40HFL40S10	400	500	0.1	10
40HFL60S02, 40HFL60S05, 40HFL60S10	600	700	0.1	10
40HFL80S05, 40HFL80S10	800	900	0.1	10
40HFL100S05, 40HFL100S10	1000	1100	0.1	10
70HFL10S02, 70HFL10S05, 70HFL10S10	100	150	0.1	15
70HFL20S02, 70HFL20S05, 70HFL20S10	200	300	0.1	15
70HFL40S02, 70HFL40S05, 70HFL40S10	400	500	0.1	15
70HFL60S02, 70HFL60S05, 70HFL60S10	600	700	0.1	15
70HFL80S05, 70HFL80S10	800	900	0.1	15
70HFL100S05, 70HFL100S10	1000	1100	0.1	15
85HFL10S02, 85HFL10S05, 85HFL10S10	100	150	0.1	20
85HFL20S02, 85HFL20S05, 85HFL20S10	200	300	0.1	20
85HFL40S02, 85HFL40S05, 85HFL40S10	400	500	0.1	20
85HFL60S02, 85HFL60S05, 85HFL60S10	600	700	0.1	20
85HFL80S05, 85HFL80S10	800	900	0.1	20
85HFL100S05, 85HFL100S10	1000	1100	0.1	20

① Types listed are cathode case, for anode case add "R" to code, i.e. 40HFLR20S02, 85HFLR100S05 etc.

Reverse recovery characteristics

	40HFL...			70HFL...			85HFL...			Units	Conditions
	S02	S05	S10	S02	S05	S10	S02	S05	S10		
t_{rr} Typical reverse recovery time	70	180	350	60	150	290	50	120	270	ns	$T_J = 25^\circ\text{C}$, $I_F = 1\text{A}$ to $V_R = 30\text{V}$ $-di_F/dt = 100\text{A}/\mu\text{s}$
	200	500	1000	200	500	1000	200	500	1000	ns	$T_J = 25^\circ\text{C}$, $-di_F/dt = 25\text{A}/\mu\text{s}$ $I_{FM} = \tau \times \text{rated } I_F(\text{AV})$
Q_{RR} Typical reverse recovered charge	160	750	3100	90	500	1600	70	340	1350	nC	$T_J = 25^\circ\text{C}$, $I_F = 1\text{A}$ to $V_R = 30\text{V}$ $-di_F/dt = 100\text{A}/\mu\text{s}$
	240	1300	6000	240	1300	6000	240	1300	6000	nC	$T_J = 25^\circ\text{C}$, $-di_F/dt = 25\text{A}/\mu\text{s}$ $I_{FM} = \tau \times \text{rated } I_F(\text{AV})$

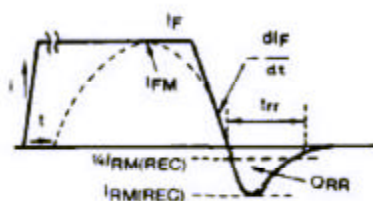
Forward conduction

	40HFL	70HFL	85HFL	Units	Conditions
$I_F(\text{AV})$ Maximum average forward current	40	70	85	A	180°C conduction, half sine wave, max. $T_c = 75^\circ\text{C}$
$I_F(\text{RMS})$ Maximum RMS forward current	63	110	134	A	
I_{FRM} Maximum peak repetitive forward current	220	380	470	A	Sinusoidal half wave, 30° conduction
I_{FSM} Maximum peak, one cycle non-repetitive forward current	400	700	1100	A	$t = 10\text{ms}$ Sinusoidal half-wave 100% V_{RRM} reapplied, initial $T_J = T_J \text{ max}$
	420	730	1151	A	$t = 8.3\text{ms}$
	475	830	1308	A	$t = 10\text{ms}$ Sinusoidal half-wave no voltage reapplied, initial $T_J = T_J \text{ max}$
	500	870	1369	A	$t = 8.3\text{ms}$
I^2t Maximum I^2t for fusing	800	2450	6050	A^2s	$t = 10\text{ms}$ 100% V_{RRM} reapplied initial $T_J = T_J \text{ max}$
	730	2240	5523	A^2s	$t = 8.3\text{ms}$
	1130	3460	8556	A^2s	$t = 10\text{ms}$ No voltage reapplied initial $T_J = T_J \text{ max}$
	1030	3160	7810	A^2s	$t = 8.3\text{ms}$
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing ①	11 300	34 650	85 560	A^2/s	$t = 0.1$ to 10ms , no voltage reapplied
$V_F(\text{TO})$ Maximum value of threshold voltage	1.081	1.085	1.128	V	$T_J = 125^\circ\text{C}$
r_F Maximum value of forward slope resistance	6.33	3.40	2.11	$\text{m}\Omega$	
V_{FM} Maximum peak forward voltage	1.95	1.85	1.75	V	$T_J = 25^\circ\text{C}$, $I_{FM} = \tau \times I_F(\text{AV})$

① I^2t for time $t_x = I^2\sqrt{t} + \sqrt{t_x}$.

THERMAL AND MECHANICAL SPECIFICATIONS

		40HFL...	70HFL...	85HFL...	Units	Conditions
T_J	Junction operating temperature range	-40 to 125			$^{\circ}\text{C}$	
T_{stg}	Storage temperature range	-40 to 150			$^{\circ}\text{C}$	
R_{thJC}	Maximum internal thermal resistance, junction to case	0.60	0.36	0.30	K/W	DC operation
R_{thCS}	Maximum thermal resistance, case to heatsink	0.25			K/W	Mounting surface, smooth, flat and greased
T	Mounting torque 10%	20 (27)			lbf•in	Lubricated threads (non-lubricated threads)
		0.23 (0.29)			kgf•m	
		2.2 (2.7)			N•m	
	to device	22			lbf•in	
		0.25			kgf•m	
		2.5			N•m	
wt	Approximate weight	25 (0.88)			g (oz)	
	Outline	DO-203AB (DO-5)				JEDEC



- I_F, I_{FM} = Peak forward current prior to commutation
 $-dI_F/dt$ = Rate of fall of forward current
 $I_{RM(REC)}$ = Peak reverse recovery current
 t_{rr} = Reverse recovery time
 Q_{RR} = Reverse recovered charge

Fig. 1 — Reverse Recovery Time Test Waveform

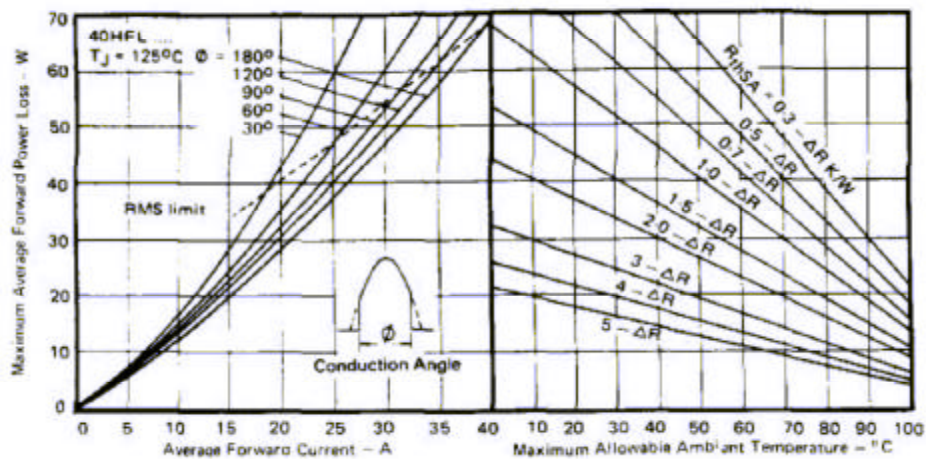


Fig. 2 - Current Rating Nomogram (Sinusoidal Waveforms), 40HFL Series

Conduction angle - ϕ	ΔR K/W
180°	0.14
120°	0.15
90°	0.20
60°	0.31
30°	0.53

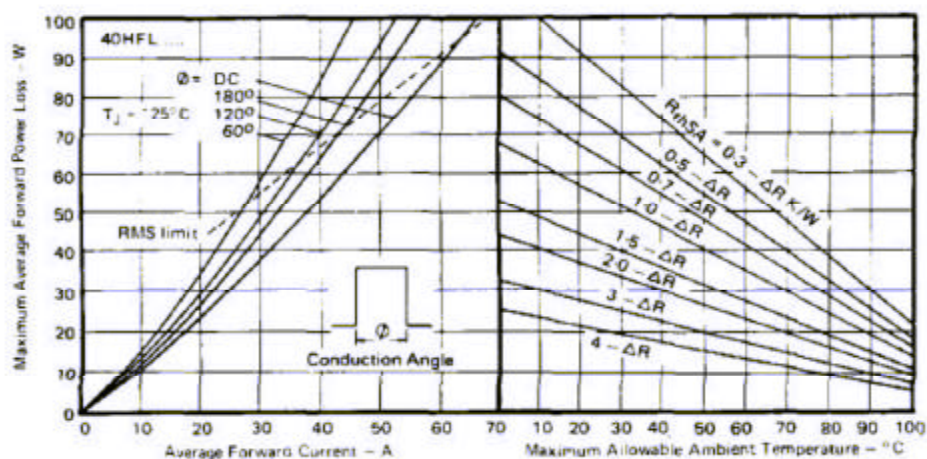


Fig. 3 - Current Rating Nomogram (Rectangular Waveforms), 40HFL Series

Conduction angle - ϕ	ΔR K/W
DC	0
180°	0.08
120°	0.14
60°	0.30

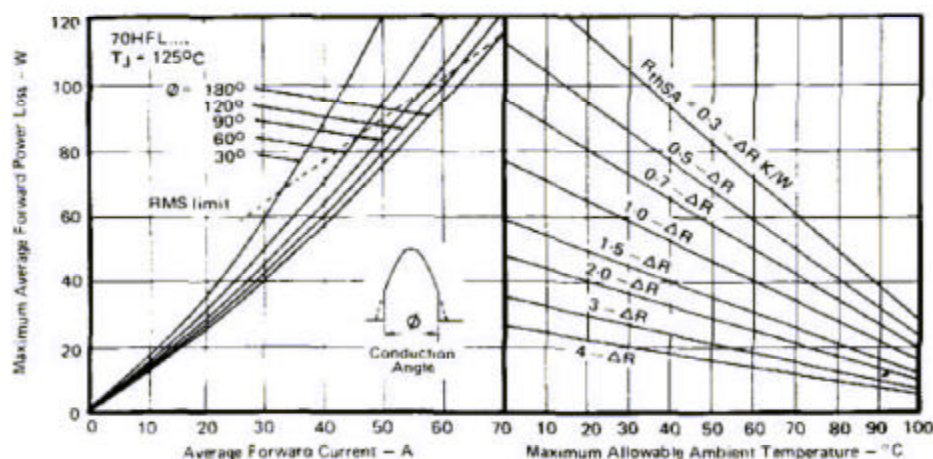


Fig. 4 - Current Rating Nomogram (Sinusoidal Waveforms), 70HFL Series

Conduction angle - ϕ	ΔR K/W
180°	0.08
120°	0.09
90°	0.12
60°	0.18
30°	0.32

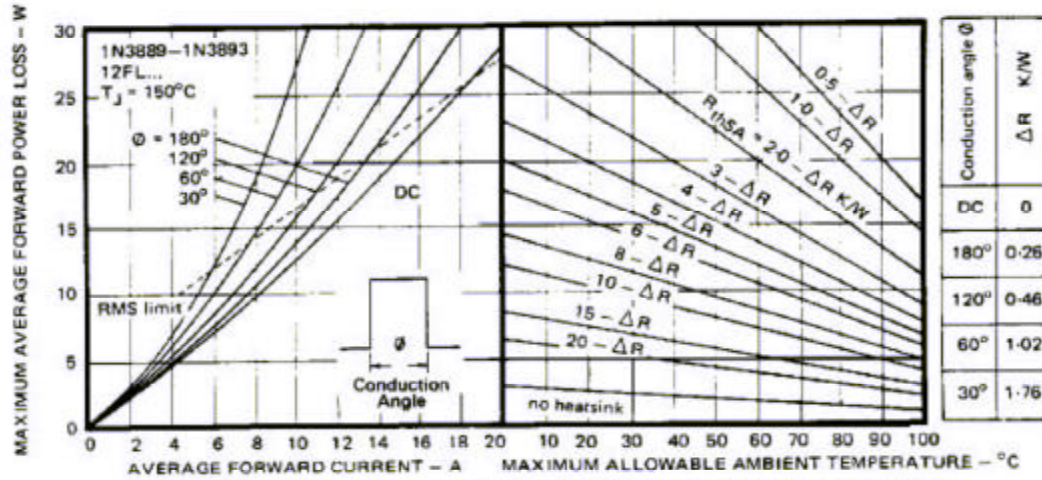


Fig. 8 - Current Rating Nomogram (Rectangular Waveforms), 1N3889 and 12FL Series

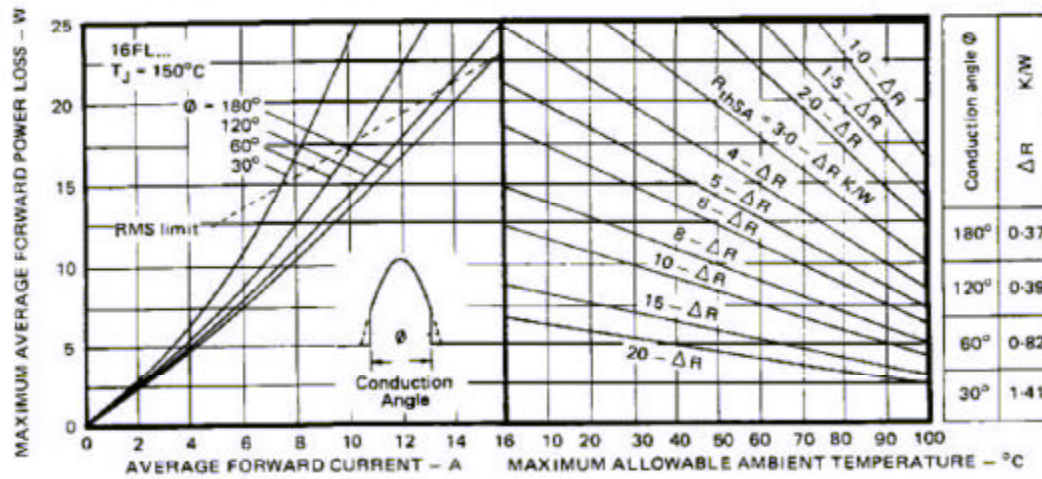


Fig. 9 - Current Rating Nomogram (Sinusoidal Waveforms), 16FL Series

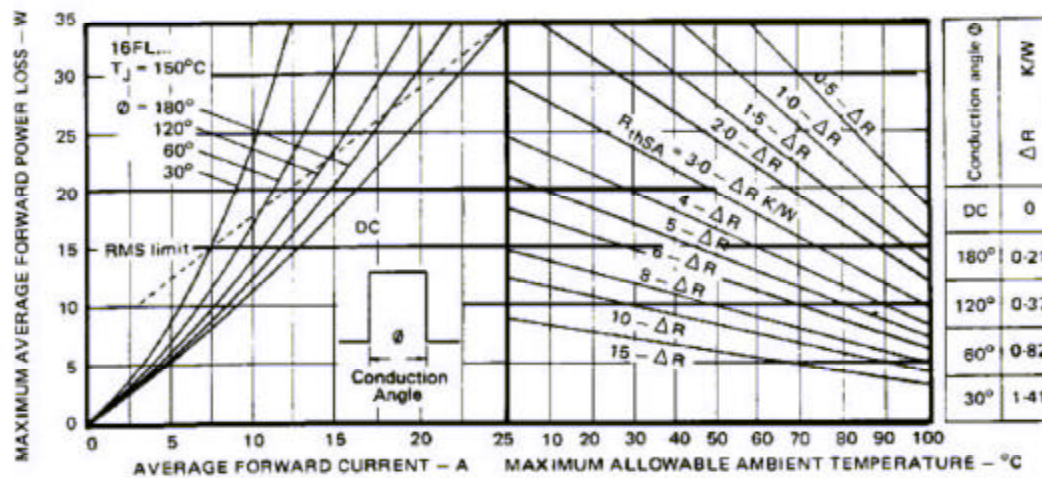


Fig. 10 - Current Rating Nomogram (Rectangular Waveforms), 16FL Series

40HFL, 70HFL, 85HFL Series

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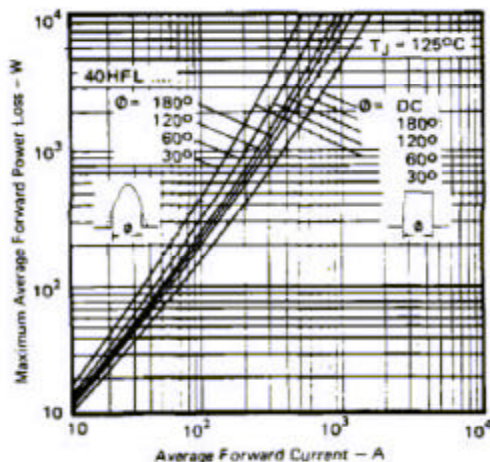


Fig. 8 - Maximum High Level Forward Power Loss Vs. Average Forward Current, 40HFL Series

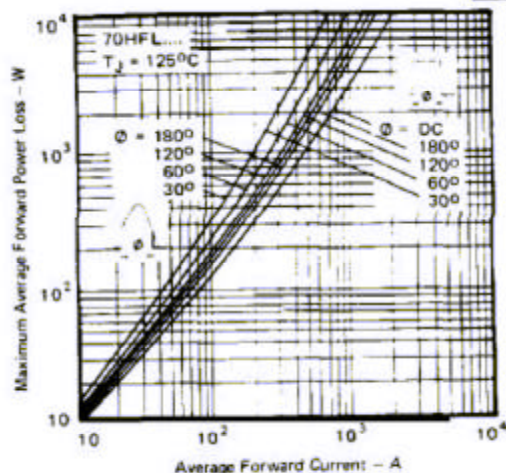


Fig. 9 - Maximum High Level Forward Power Loss Vs. Average Forward Current, 70HFL Series

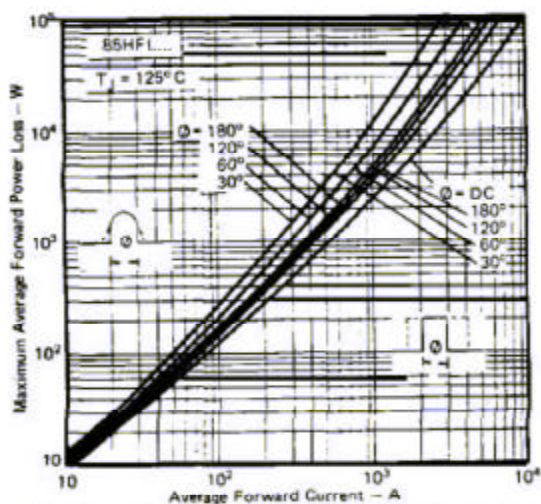


Fig. 10 - Maximum High Level Forward Power Loss Vs. Average Forward Current, 85HFL Series

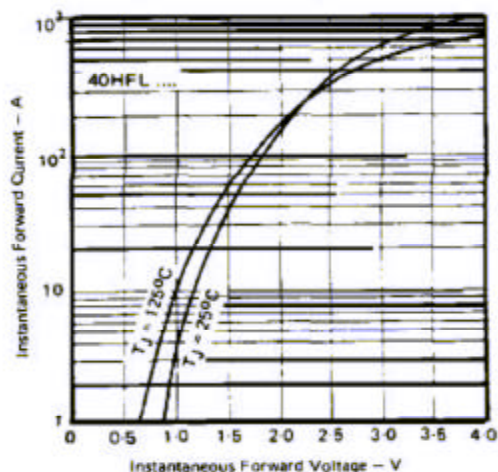


Fig. 11 - Maximum Forward Voltage Vs. Forward Current, 40HFL Series

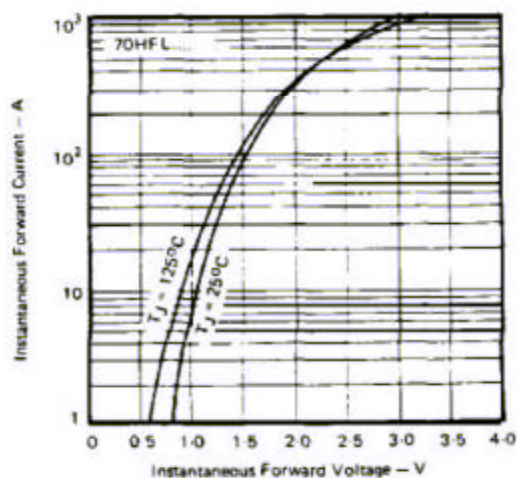


Fig. 12 - Maximum Forward Voltage Vs. Forward Current, 70HFL Series

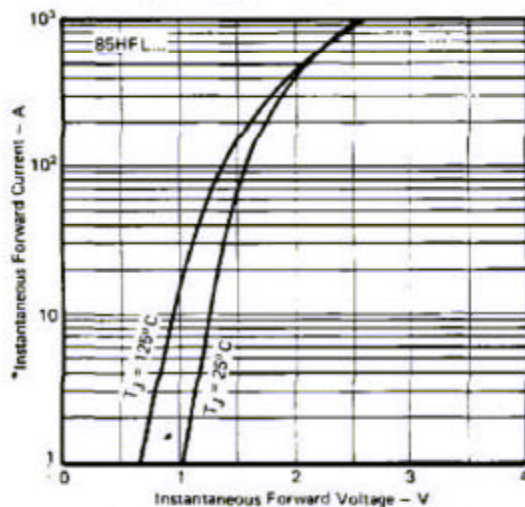


Fig. 13 - Maximum Forward Voltage Vs. Forward Current, 85HFL Series

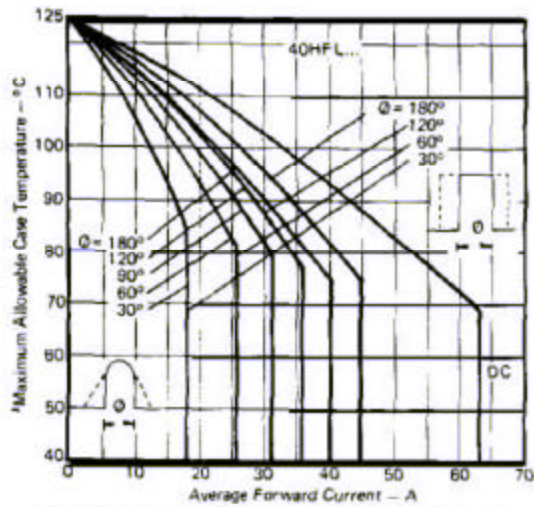


Fig. 14 - Average Forward Current Vs. Maximum Allowable Case Temperature, 40HFL Series

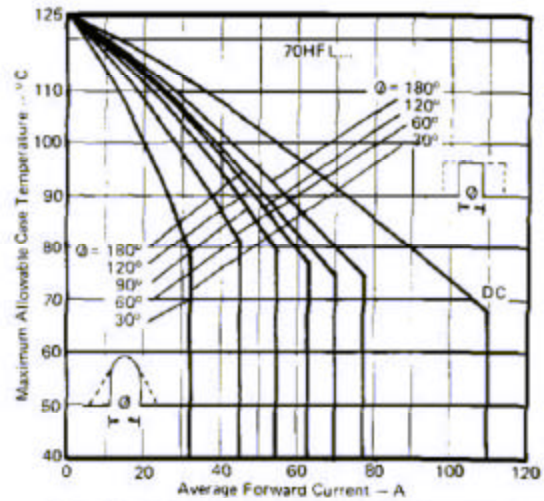


Fig. 15 - Average Forward Current Vs. Maximum Allowable Case Temperature, 70HFL Series

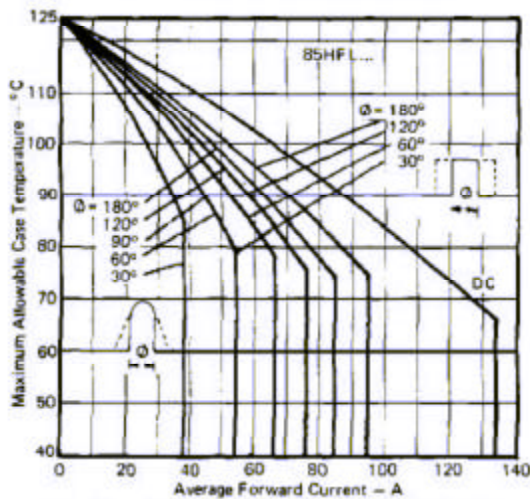


Fig. 16 - Average Forward Current Vs. Maximum Allowable Case Temperature, 85HFL Series

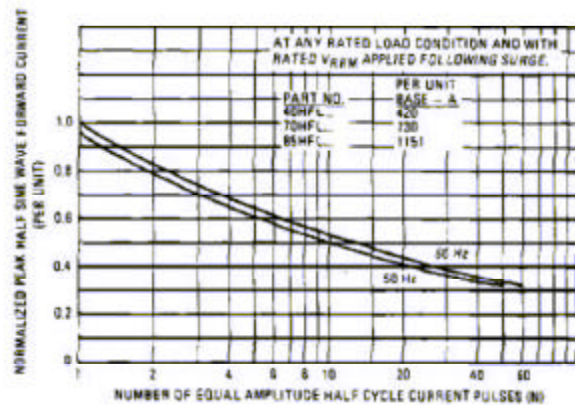


Fig. 17 - Maximum Non-Repetitive Surge Current Vs. Number of Current Pulses, All Series

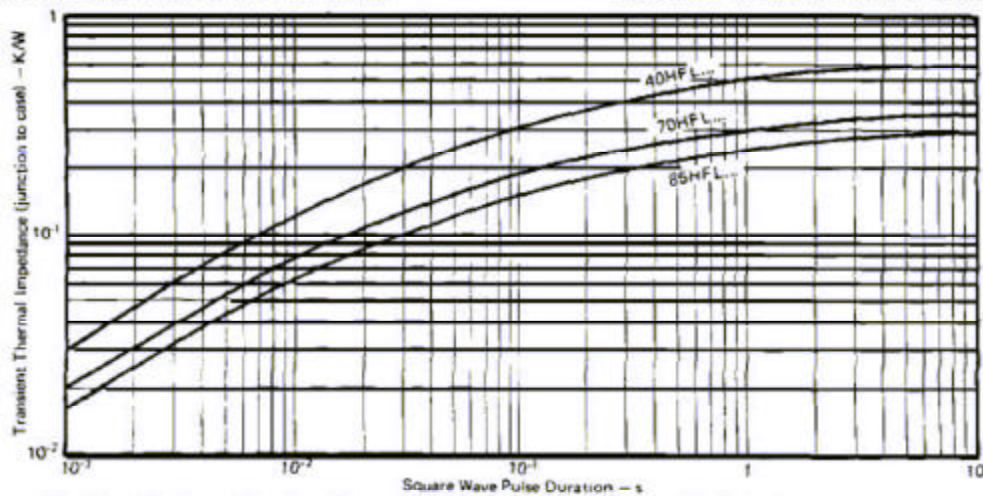


Fig. 18 - Maximum Transient Thermal Impedance, Junction-to-Case Vs. Pulse Duration, All Series

40HFL, 70HFL, 85HFL Series

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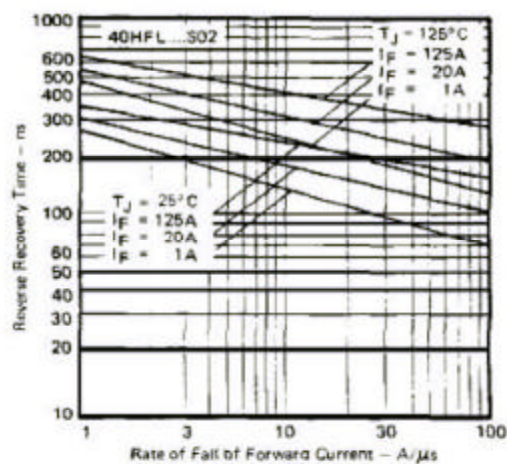


Fig. 19 - Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 40HFL_S02 Series

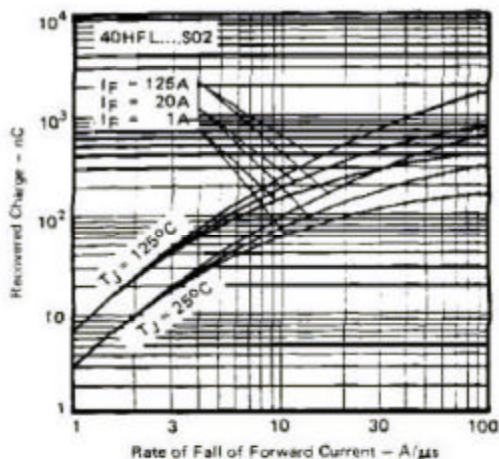


Fig. 20 - Typical Recovered Charge Vs. Rate of Fall of Forward Current, 40HFL_S02 Series

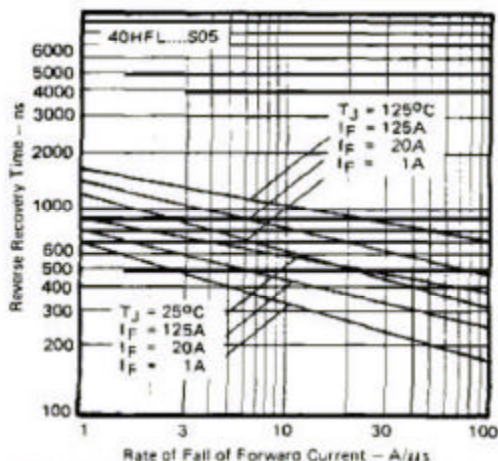


Fig. 21 - Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 40HFL_S05 Series

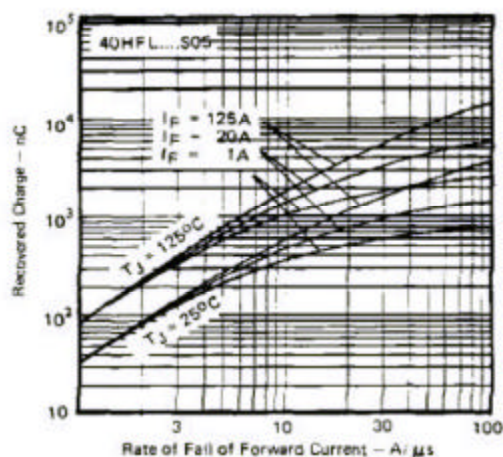


Fig. 22 - Typical Recovered Charge Vs. Rate of Fall of Forward Current, 40HFL_S05 Series

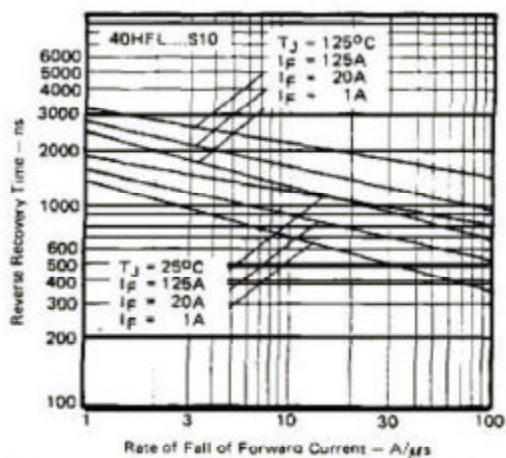


Fig. 23 - Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 40HFL_S10 Series

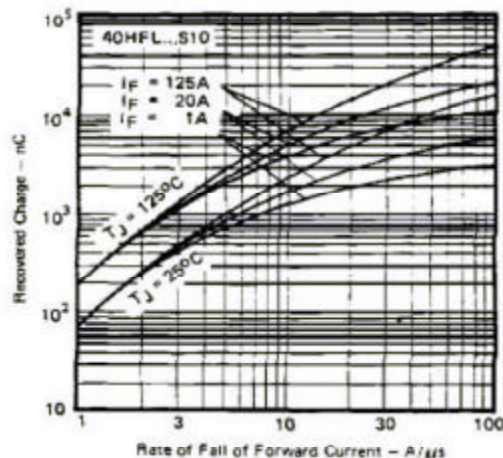


Fig. 24 - Typical Recovered Charge Vs. Rate of Fall of Forward Current, 40HFL_S10 Series

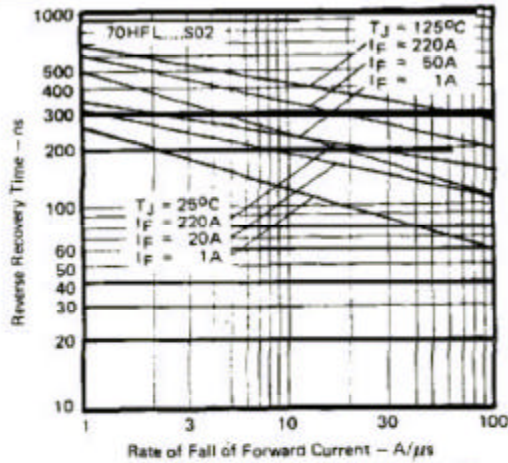


Fig. 25 — Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 70HFL_S02 Series

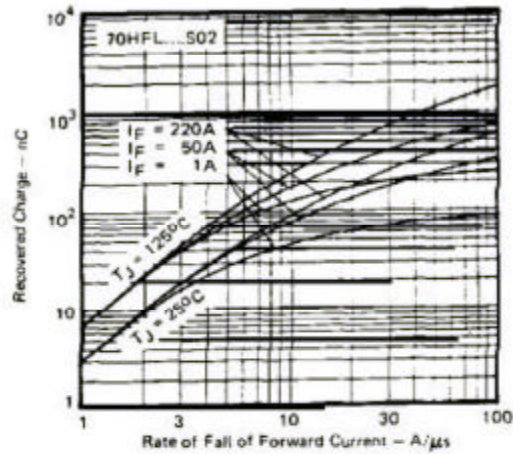


Fig. 26 — Typical Recovered Charge Vs. Rate of Fall of Forward Current, 70HFL_S02 Series

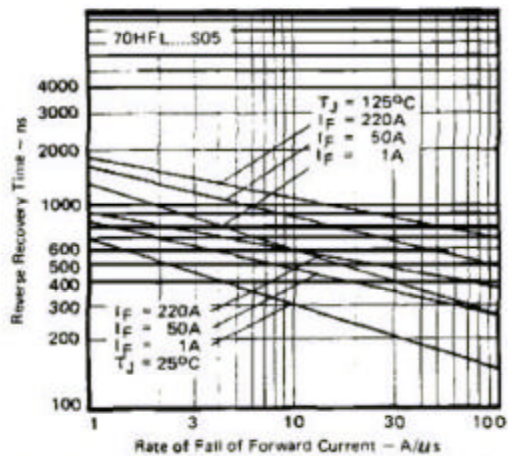


Fig. 27 — Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 70HFL_S05 Series

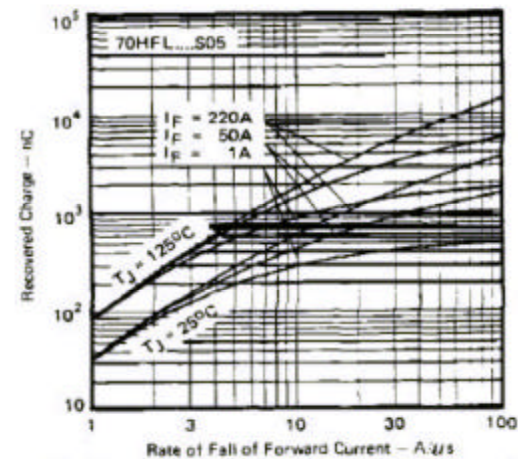


Fig. 28 — Typical Recovered Charge Vs. Rate of Fall of Forward Current, 70HFL_S05 Series

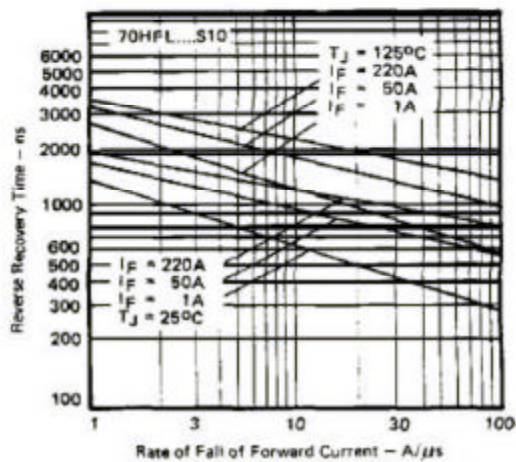


Fig. 29 — Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 70HFL_S10 Series

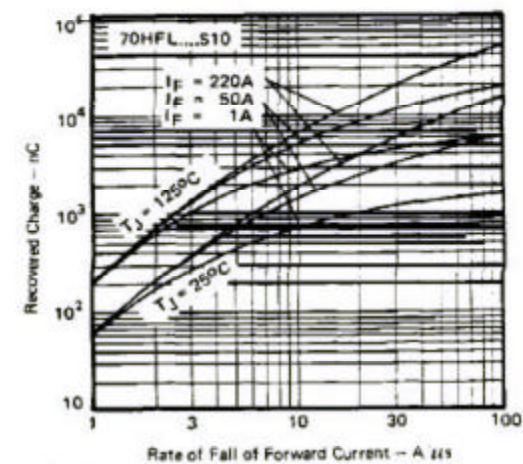


Fig. 30 — Typical Recovered Charge Vs. Rate of Fall of Forward Current, 70HFL_S10 Series

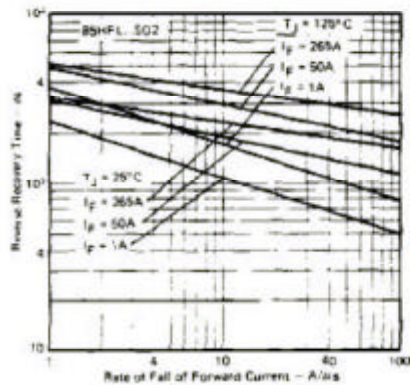


Fig. 31 - Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 85HFL_S02 Series

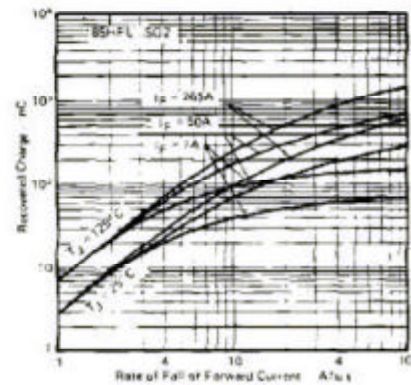


Fig. 32 - Typical Recovered Charge Vs. Rate of Fall of Forward Current, 85HFL_S02 Series

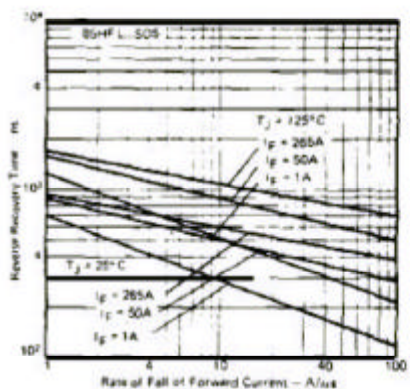


Fig. 33 - Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 85HFL_S05 Series

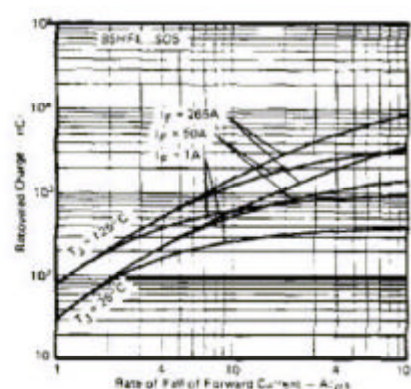


Fig. 34 - Typical Recovered Charge Vs. Rate of Fall of Forward Current, 85HFL_S05 Series

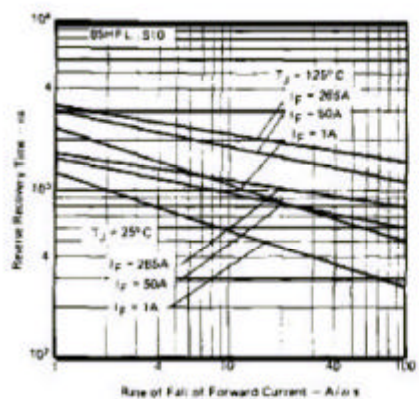


Fig. 35 - Typical Reverse Recovery Time Vs. Rate of Fall of Forward Current, 85HFL_S10 Series

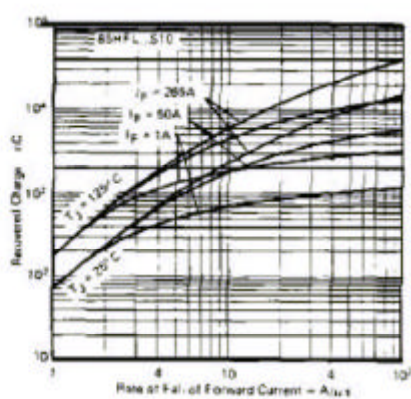


Fig. 36 - Typical Recovered Charge Vs. Rate of Fall of Forward Current, 85HFL_S10 Series



О компании

ООО "ТрейдЭлектроникс" - это оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов. Реализуемая нашей компанией продукция насчитывает более полумиллиона наименований.

Благодаря этому наша компания предлагает к поставке практически не ограниченный ассортимент компонентов как оптовыми, мелкооптовыми партиями, так и в розницу.

Наличие собственной эффективной системы логистики обеспечивает надежную поставку продукции по конкурентным ценам в точно указанные сроки.

Срок поставки со стоков в **Европе и Америке – от 3 до 14 дней.**

Срок поставки из **Азии – от 10 дней.**

Благодаря развитой сети поставщиков, помогаем в поиске и приобретении экзотичных или снятых с производства компонентов.

Предоставляем спец цены на элементы для создания инженерных сэмплов.

Упорный труд, качественный результат дают нам право быть уверенными в себе и надежными для наших клиентов.

Наша компания это:

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- Широкий ассортимент
- Минимальные сроки поставок
- Техническая поддержка
- Подбор комплектации
- Индивидуальный подход
- Гибкое ценообразование

Наша организация особенно сильна в поставках модулей, микросхем, пассивных компонентов, ксайленсах (XC), EPF, EPM и силовой электроники.

Большой выбор предлагаемой продукции, различные виды оплаты и доставки, позволят Вам сэкономить время и получить максимум выгоды от сотрудничества с нами!

Перечень производителей, продукцию которых мы поставляем на российский рынок





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